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Visualizing copper assisted graphene growth in nanoscale

SUBJECT AREAS:

TWO-DIMENSIONAL
MATERIALS

SYNTHESIS OF GRAPHENE

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Control synthesis of high quality large-area graphene on transition metals (TMs) by chemical vapor deposition (CVD) is the most fascinating approach for practical device applications. Interaction of carbon atoms and TMs is quite critical to obtain graphene with precise layer number, crystal size and structure. Here, we reveal a solid phase reaction process to achieve Cu assisted graphene growth in nanoscale by in-situ transmission electron microscope (TEM). Significant structural transformation of amorphous carbon nanofiber (CNF) coated with Cu is observed with an applied potential in a two probe system. The coated Cu particle recrystallize and agglomerate toward the cathode with applied potential due to joule heating and large thermal gradient. Consequently, the amorphous carbon start crystallizing and forming sp^2 hybridized carbon to form graphene sheet from the tip of Cu surface. We observed structural deformation and breaking of the graphene nanoribbon with a higher applied potential, attributing to saturated current flow and induced Joule heating. The observed graphene formation in nanoscale by the in-situ TEM process can be significant to understand carbon atoms and Cu interaction.

Since the first isolation of graphene, two dimensional materials has been gaining significant attention in various prospective of device applications^{1–6}. Over the last few years, significant development on graphene synthesis technology has been witnessed, bringing new ideas of innovation for device integration^{7–12}. Synthesis of large-area high quality graphene by atmospheric or low pressure CVD process is one of the most fascinating aspect in graphene technology^{10–17}. Continuous single layer graphene film and single crystal domains have been synthesized by the CVD process on TMs substrate^{10–12,15–21}. In prospect to achieve control graphene growth, understanding of carbon atoms and metal surface interaction during growth process is of great interest. Theoretical and experimental studies were progressing to understand graphene formation process on TMs surface by a CVD technique^{22–25}. Exploring carbon atoms interaction with TMs in nanoscale can be also significant to visualize graphene growth process. Subsequently, it can give an insight in a solid source reaction process of graphene growth in presence of TMs.

In-situ TEM study of carbon materials is of great interest to explore the physical properties and chemical structural transformation process in nanoscale^{26–30}. Structural transformation of carbon nanotubes (CNTs) has been considerably investigated by the in-situ TEM^{31–34}. Previously, Ichihashi et al. has reported transformation of Fe-doped amorphous carbon into graphitic tubular structure after annealing at 650–900°C³². Again, electrochemical sodiation process and microstructure evolution of individual Co9S8-filled CNTs have been explored by in-situ TEM³³. Similarly, we have observed polycrystalline carbon nanofiber (CNF) transformation to an onion-ring-like graphitized structure by an in-situ TEM field emission (FE) process³⁴. Recently, we observed FE-induced structural change of Fe incorporated CNF by in-situ TEM³⁵. In the FE measurements, dramatic transformation of the amorphous Fe-incorporated CNF was observed to form a hollow graphitic nanostructure with migration of Fe particle. The significant structural change was obtained owing to bulk diffusion process of carbon atoms in highly soluble Fe nanoparticles with joule heating effect. It is quite interesting to investigate how the solid phase reaction will be occur in case of low carbon solubility TMs. In this prospect, we demonstrated structural transformation mechanism of Au-incorporated CNF to determine catalytic ability of Au for graphitization³⁶.

However, any of the previous in-situ TEM studies did not realize graphene sheet formation in presence of TMs. Considering the possibility of graphene growth by in-situ TEM, we explored the electrical conduction behavior of CNF coated Cu in a two probe system. The coated Cu particle recrystallize and agglomerate with applied electric field and move toward cathode. Consequently, the amorphous carbon atoms of CNF convert to sp^2 hybridized

Figure 1 | (a) Schematic diagram of the in-situ TEM I-V measurement setup. (b) I-V characteristic of the Cu coated CNF as measured by the two probe system at lower applied potential.

carbon in presence of Cu to form graphene structure. In what follows, we demonstrate Cu and carbon atoms interaction in nanoscale, achieving graphene nanoribbon growth by in-situ TEM.

Results and discussion

Fig. 1a shows a schematic diagram of the in-situ current-voltage (I-V) measurement setup. A tungsten nanoprobe controlled by nano-manipulator was used as anode in the in-situ experimental process. On the other hand, CNF prepared on a graphite foil by argon ions (Ar^+) irradiation at room temperature as reported elsewhere was taken as the cathode³⁴. The CNF prepared by ion irradiation was coated with Cu to investigate the Cu and carbon interaction with applied bias potential. The structural transformation of the Cu-coated CNF (Cu-CNF) of the cathode was visualized by in-situ TEM in nanoscale by applying bias potential. The pressure in the specimen chamber was about 10^{-5} Pa in the I-V measurement process. We investigated the morphological change with lower and higher bias voltage. Fig. 1b shows an I-V characteristic of the Cu-CNF as measured by the two probe system. The high resistance of amorphous CNF significantly affect the flow of current (maximum current flow $\sim 10^{-5}$ A) at lower applied potential.

Fig. 2a shows a TEM image of the Cu-CNF sample created on the graphitic plate. The image shows that CNF are around 100–500 nm in length, fully coated with polycrystalline Cu particles. Fig. 2b shows a TEM image at the contact of nanoprobe and Cu-CNF. In a low current flow through the Cu-CNF also induced joule heating effect was observed. Poor crystalline graphene sheet was formed from the surface contact with resistive joule heating effect. Fig. 2c shows a TEM image of low crystalline few-layers graphene sheet. The amorphous carbon from the CNF recrystallize to form sp^2 carbon in presence of Cu, while the Cu particles start agglomerating toward the cathode. The interesting effect of graphene formation in presence of

Figure 2 | TEM image of (a) Cu-CNF sample created on the graphitic plate, (b) graphitization at the contact of nanoprobe and Cu-CNF after applying low bias potential. (c) Higher resolution image of the low crystalline few-layers graphene sheet.

Figure 3 | (a) I-V curve of the Cu-CNF with higher bias voltage in the two probe system (0–1.8 V). (b) – (g) TEM images of the Cu-CNF with change in applied potential from 0.0–1.8 V as that of the I-V characteristics. TEM images presenting the structural transformation with gradual increase in applied potential. Formation of a graphene nanoribbon across the cathode and anode is obtained with a length of around ~300 nm and width ~50 nm.

Cu was further investigated with higher applied potential to understand the growth process.

Fig. 3a shows an I-V curve of the Cu-CNF with higher bias voltage in the two probe system. It was observed that there was no significant current flow through the CNF at an applied voltage up to 1 V. There is a sharp rise in current flow with significant drop of resistance from 340 K Ω to 15.3 K Ω . Applying more than 1 V saturated current flow was obtained. We observed significant structural transformation of the Cu-CNF with higher current flow and induced joule heating. Fig. 3b–g shows TEM image of the Cu-CNF with change in applied potential from 0.0–1.8 V as that of the I-V characteristics. As shown in fig. 3b, initially the Cu-CNF is connected to tungsten nanoprobe to investigate the structural transformation with gradual increase in applied potential. Fig. 3c shows that with increase in bias voltage graphene like structure were formed with Cu particles moving toward cathode from nanoprobe contact. Increase the applied voltage much further, nanoribbon like graphene structure grow with agglomeration of Cu toward cathode as shown in fig. 3c–g. Finally, we achieve to grow a graphene nanoribbon of the length around ~300 nm and width ~50 nm by the in-situ TEM. The observed growth process of graphene nanoribbon like structure with induced joule heating effect is significant to understand Cu interaction with carbon atoms. The observed graphene growth phenomena is considerably different than that of carbon nanotube growth in presence of Fe nanoparticle by an in-situ TEM field emission process. In our

previous study of Fe-incorporated CNF case, Joule heating caused by the FE-process and CNT-like hollow structure was obtained with electromigration of Fe particles³⁵. We have also performed additional two probe contact I-V measurement for Fe-incorporated CNF similar to that of Cu-CNF. In this experiment also we observed formation of bamboo-like CNTs structure with migration of Fe particles (supplementary information figure S2). The growth of graphene nanoribbon in case of Cu-CNF is explained as follows. In the two probe system current flows across the anode and cathode, where a thermal gradient can generate at the contact of anode and CNF tips. The thermal gradient across the cathode and anode act as the driving force for migration of Cu³⁷. Subsequently, Cu-induced graphitization and graphene growth occurs from the amorphous CNF due to joule heating. Carbon atoms can absorb or diffuse on Cu surface rather than bulk diffusion in the graphene formation process. The ability to form different allotropes of sp^2 crystalline carbon significantly depends on the carbon solubility with various transition metals and affinity. Considering the fact that Fe has much higher carbon affinity than that of Cu, the reaction and graphitization process can be significantly different. The filled 3d-electron shell [Ar]4s¹3d¹⁰ of Cu suggests low reactivity with carbon and not assisting formation of carbide phase³⁸. Thus, the reaction of carbon atoms and transition metals is a crucial factor in nanocarbon formation. In this prospect, carbon and Cu interaction in graphene growth was further investigated at the edge of nanoparticle by high resolution TEM studies.

Figure 4 | TEM image of the Cu structure (a) before and (b) after applied bias voltage. (c) TEM image at the tip of the Cu grain, presenting the dissolution of carbon atoms to form graphene nanoribbon structure.

Fig. 4a–b shows TEM image of the Cu structure before and after applied bias voltage. The thermally evaporated Cu at room temperature shows polycrystalline structure with low crystallinity. Recrystallization of Cu occurs with induced joule heating during the applied bias voltage. The transformation of polycrystalline Cu structure and crystalline nature is shown in fig. 4b. The crystalline plane of Cu grain became more pronounced with recrystallization due to heating effect. While, we observed poorly graphitized layer structures at the surrounding of the polycrystalline Cu grains. This result suggests that with joule heating effect the carbon atoms can absorb on Cu grains to recrystallize and form sp^2 hybridized carbon. Increasing the bias voltage and thereby the joule heat, absorb carbon atoms significantly crystallize to create graphene structure. Fig. 4c shows a TEM image at the tip of Cu grain. Remarkably, the polycrystalline Cu grains start agglomerating toward the Cu rich cathode with joule heating. In the meantime, the absorbed carbon atoms desorbed from the Cu surface to create highly crystalline graphene structure. We include a video visual of the graphene growth process observed by the in-situ TEM study (Multimedia view 1).

Fig. 5a shows a TEM image after complete growth of the graphene nanoribbon. The result can be significant to understand Cu and carbon atoms interaction in nanoscale for graphene growth process. The obtained graphene structure was further confirmed by high resolution TEM images. Fig. 5b–c shows TEM studies of sheet like structure of the synthesized graphene ribbon, in contrast to hollow tube like structure of previous reports. The carbon atoms created sp^2 hybridized structure catalyzed by Cu to form a sheet like structure rather than CNT. An inter-planer spacing of about 0.34 nm is estimated for the graphene layers, corresponding to graphite (0002) spacing. In most of the previous studies, structural transformation of CNF and CNTs by in-situ TEM has been demonstrated. However, Cu assisted graphene growth by in-situ TEM was not achieved. The interesting results observed in these studies can provide more light on Cu and carbon interaction for graphene growth process.

Further, effect of higher applied potential across the cathode and anode after complete growth of the graphene nanoribbon was investigated by the in-situ TEM. The nature of graphene-metal contact has significant importance to investigate the Joule heating effect, current

Figure 5 | TEM image (a) after complete growth of the graphene nanoribbon, (b), (c) sheet like structure of the synthesized graphene ribbon, in contrast to hollow tube like structure. The carbon atoms created sp^2 hybridized structure catalyzed by Cu to form a sheet like structure rather than CNT.

crowding and thermoelectric heating process in electronic devices. According to general prospective Joule heating can be explained from a simple semi-classical picture in which electrons collide with the atoms of a conductor, generating heat locally at low dimension. It has been also observed that stable heating up to 2000 K occurred in an individual multiwalled carbon nanotube induced by field emission current³⁹. However, in this case, we did not observe evaporation of Cu by joule heating effect at a higher vacuum, which signifies less induced joule heating. Fig. 6a shows I-V characteristic with a higher applied potential across the anode and cathode. We observe gradual increase in current flow and structural transformation amorphous carbon catalyzed by Cu to form graphene structure. However, the graphene nanoribbon broke at middle part after growth of around ~300 nm in length as shown in fig. 6b–c. A saturation current of 0.119 mA was flown through the graphene nanoribbon with an applied bias potential of 2 V. A sharp decrease in current was observed with the saturation current flow and increase in applied voltage. Fig. 6c shows the TEM image of the broken and disconnected graphene sheets. We also include a video clip for the graphene deformation process as observed by the in-situ TEM study (Multimedia view 2). The breaking of the graphene can be explained with generation of high joule heat with flow of saturated current at low dimension. This indicates that significant amount heat can generate at the low dimensional metal-metal contact and thereby affecting the highly stable and crystalline graphene based materials.

Conclusion

In conclusion, we have revealed the solid phase reaction process of Cu and carbon atoms to grow graphene nanoribbon by in-situ TEM. Structural transformation of amorphous CNF coated with Cu was investigated in nanoscale with applied bias in a two probe system. Significant interaction of Cu and carbon atoms was visualized to achieve Cu-assisted graphene structure formation. The coated Cu particles recrystallize with applied potential and agglomerate toward the cathode with joule heating effect and thermomigration. In this process, the amorphous carbon of CNF also started crystallizing and forming sp^2 hybridized carbon to form graphene nanoribbon activated by the Cu particles. We were able to grow the graphene nanoribbon around ~300 nm in length across the cathode and anode of in-situ TEM. The observed graphene formation in nanoscale by the in-situ TEM process can be significant to understand carbon atoms

Figure 6 | (a) I-V characteristic with a higher applied potential across the anode and cathode. (b) TEM image of breaking the graphene at middle part after growth of around ~ 300 nm in length. (c) Higher resolution TEM image of the broken and disconnected graphene sheets.

and Cu interaction. We also observed deformation and broking of the graphene nanoribbon with high applied potential attributing to current crowding and Joule heating effect in nanoscale.

Methods

Synthesis of CNF by ion irradiation. For the CNF preparation, we used a commercially available graphite foils with a dimension of $5\text{ mm} \times 20\text{ mm} \times 100\text{ }\mu\text{m}$ and Kaufmann-type ion gun (Iontech. Inc. Ltd., model 3-1500-100FC) for growing CNF. The oblique Ar^+ bombardment is known to be more suitable for the growth of ion-induced CNF than the normal incidence. The edges of the graphite foils were irradiated with argon ions (Ar^+) at 45 degree from normal to the surface for 45 min at room temperature. The diameter and ion beam energy employed for this experiment were 6 cm and 1 keV, respectively. The basal and working pressures were 1.5×10^{-5} and 2.0×10^{-2} Pa, respectively. The growth mechanism of ion-induced CNF was explained elsewhere in detail³⁴.

Cu coated CNF sample preparation. Cu was coated by thermal evaporation on the fabricated CNF on graphite foil. Cu coating was carried out with ULVAC VPC-260F thermal evaporator. Later the Cu coated graphite plate was cut into small sizes of 2 mm width and directly mounted on the TEM sample holder without any additional post-treatment to observe the structure transformation and crystallinity of Cu-CNF.

In-situ TEM and I-V measurements. The TEM analysis was performed by JEOL JEM-2010 with vacuum chamber pressure less than 2.5×10^{-5} Pa. We used a TEM sample holder (JEOL; EM-Z02154T) with a tungsten nanoprobe controlled by nano-manipulator and electrical biasing equipment which allowing us to observe the morphological transformation of the Cu coated CNF sample. The crystalline structure of Cu and amorphous carbon with applied potential of the prepared Cu-CNF is explored.

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Author contributions

The experiments were carried out by M. R., M. Y., Y.Y. and C.T. discussing with M.T. and G.K. The manuscript was prepared by G.K. and M.T. discussing the results and experimental conditions with all other authors. All authors have given approval to the final version of the manuscript.

Additional information

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